

View Online at <https://aerobasegroup.com/nsn/5961-00-115-8561>

Inclosure Material:

Glass

Overall Length:

0.700 millimeters

Terminal Length:

0.200 millimeters

Mounting Facility Quantity:

3

Mounting Method:

Terminal

Terminal Circle Diameter:

0.209 millimeters

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

30.0 breakdown voltage, collector to emitter, sustained and 60.0 breakdown voltage, collector-to-base, emitter open

Current Rating Per Characteristic:

50.00 nanoamperes zero-gate-voltage source current preset

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-emitter absolute

Maximum Operating Temperature Per Measurement Point:

-55.0 degrees celsius case and 175.0 degrees celsius case

Special Features:

High frequency low power silicon npn bjt; junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

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